## Features

- Broadband Performance
- Low Loss:

$$
\begin{aligned}
& \mathrm{TX}=0.35 \mathrm{~dB} @ 3.5 \mathrm{GHz} \\
& \mathrm{RX}=0.4 \mathrm{~dB} @ 3.5 \mathrm{GHz}
\end{aligned}
$$

- High Isolation:
$\mathrm{RX}=45 \mathrm{~dB} @ 3.5 \mathrm{GHz}$
- Up to 70 W CW Power Handling $@+105^{\circ} \mathrm{C}$
- Fast Switching Speed
- Single +5 V DC Supply
- Compatible with 1.8 V and 3.3 V logic
- Lead-Free 5 mm 20-Lead HQFN Package
- RoHS* Compliant


## Applications

- TDD 4G/5G Macro Base Stations
- Aerospace and Defense
- TDD-based communication systems


## Description

The MAMF-011180 is a high power broadband PIN diode SPDT switch with a 5 V power management chip designed for 0.5 to 7.2 GHz high power applications.

The device features low insertion loss, high isolation with low DC power consumption. It has an integrated bias controller utilizing a boost circuit. This switch requires only a single 5 V supply, and a single TX / RX control signal that is compatible with 1.8 V or 3.3 V logic.

## Ordering Information ${ }^{1}$

| Part Number | Package |
| :---: | :---: |
| MAMF-011180-TR1000 | 1000 Piece Reel |
| MAMF-011180-001SMB | Sample Board |

[^0]
## Functional Schematic



## Pin Configuration

| Pin \# | Function |
| :---: | :---: |
| $1,4,5,7,11,19$ | Ground |
| 2 | No Internal Connection ${ }^{2}$ |
| 3 | RF Input |
| 6 | RX Output / Series Bias |
| 8 | RX Shunt Bias |
| 9 | RX Shunt Driver Output |
| 10 | RX Series Driver Output |
| 12 | DC-DC Comp |
| 13 | DC-DC Boost Voltage |
| 14 | DC-DC VUREC |
| 15 | 5 V Supply |
| 16 | T/R Logic Control |
| 17 | TX Driver Output |
| 18 | TX Output / Bias |
| 20 | Paddle $^{3}$ |
| 21 |  |

2. Pin 2 may be connected to the ANT trace on a PCB without affecting the performance.
3. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.
[^1]
## Pin Description

| Pin \# | Name | Description |
| :---: | :---: | :--- |
| $1,4,5,7,11,19$ | GND | These pins are grounded internally. |
| 2 | N/C | Not connected internally. May be connected to the ANT trace on a PCB without affecting <br> RF performance. |
| 3 | ANT | Antenna RF Port and DC Bias input pin, requires resistors and choke inductor to set the <br> diode bias current and DC blocking cap. |
| 6 | RX | RX output port and RX series diode DC bias input pin, requires choke inductor for bias and <br> DC blocking cap. |
| 8 | RX BIAS | RX shunt diode bias input pin, requires choke inductor for bias and decoupling cap. |
| 9 | RXD BIAS | Driver output voltage pin for RX shunt diode, requires resistors to set the bias current. |
| 10 | RXD | Driver output voltage pin for RX series diode. |
| 12 | COMP | Internal DC boost compensation pin. |
| 13 | FB | Internal DC boost feedback Pin. |
| 14 | VREC | Rectified output voltage pin of the internal DC boost. |
| 15 | VUREC | Unrectified output voltage pin of the internal DC boost. |
| 16 | VCC | 5V Supply for Internal DC boost and driver, requires decoupling capacitors |
| 17 | VCTRL | T/R switching logic control. |
| 18 | TXD | Driver output voltage pin for TX diode. |
| 20 | TX | TX Input or 50 Ohm load port and DC bias input pin, requires choke inductor for bias and <br> DC blocking cap. |
| 1 | Ground ${ }^{3}$ |  |
| 10 |  |  |

Electrical Specifications: Freq. $=3.5 \mathrm{GHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}, \mathrm{Z}_{0}=50 \Omega$,
TX mode: ANT to TX ON, $\mathrm{V}_{\text {ctrl }}=1.2 \mathrm{~V}, \mathrm{~V}_{\mathrm{cc}}$ Current $=150 \mathrm{~mA}^{4}$;
RX mode: ANT to RX ON, $\mathrm{V}_{\text {CTRL }}=0.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{cc}}$ Current $=100 \mathrm{~mA}^{4}$;

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | ANT to TX ON <br> ANT to RX ON | dB | - | 0.3 | 0.6 |
| Isolation | ANT to RX (TX mode) <br> ANT to TX (RX mode) | 0.4 | 0.8 |  |  |
| ANT Input Return Loss | ANT to RX ON <br> ANT to TX ON | dB | 37 | 45 | - |
| TX Output Return Loss | ANT to TX ON | -17 |  |  |  |

4. The average current is set with external resistors: $R 1, R 2, R 3$, and $R 4$ as shown in the sample board schematic. The resistor values can be adjusted higher to reduce the $\mathrm{V}_{\mathrm{Cc}}$ average current.

## Maximum Operating Conditions

| Parameter | Operating Maximum |
| :---: | :---: |
| RF Input Power C.W. | $48.5 \mathrm{dBm} @+105^{\circ} \mathrm{C}$, <br> $3.6 \mathrm{GHz}, \mathrm{VSWR}=1.2: 1$ |
| $\mathrm{~V}_{\mathrm{CC}}$ | 4.5 V to 5.5 V |
| Junction Temperature ${ }^{5}$ Switch | $+175^{\circ} \mathrm{C}$ |
| Junction Temperature 6,7 <br> Integrated Bias Controller | $+125^{\circ} \mathrm{C}$ |
| Case (Paddle) Temperature | $-40^{\circ} \mathrm{C}$ to $+120^{\circ} \mathrm{C}$ |
| Storage Temperature | $-55^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

5. 5. Operating at nominal conditions with $\mathrm{T}_{\mathrm{J}} \leq+175^{\circ} \mathrm{C}$ will ensure MTTF > $1 \times 10^{6}$ hours.
1. Operating at nominal conditions with $\mathrm{T}_{J} \leq+125^{\circ} \mathrm{C}$ will ensure MTTF $>1 \times 10^{5}$ hours.
2. Absolute maximum junction temperature of $150^{\circ} \mathrm{C}$; exceeding this temperature may cause permanent damage to the device. MACOM does not recommend sustained operation near this temperature.

## PCB Layout



## Truth Table

| ANT - TX | ANT - RX | VCTRL |
| :---: | :---: | :---: |
| ON | OFF | HIGH (1.2-3.6 V) |
| OFF | ON | LOW $(0-0.6 \mathrm{~V})$ |

## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

| Parameter | Rating | Standard |
| :---: | :---: | :---: |
| Human Body <br> Model (HBM) | $500 ~ V$ <br> (Class 1B) | ESDA / JEDEC <br> JS-001 |
| Charged Device <br> Model (CDM) | $1000 ~ V$ <br> (Class C3) | JEDEC <br> JESD22-C101 |

## Application Schematic

NOTE: Contact factory for sample board layout including considerations for thermal dissipation through the PCB.


## Switch Biasing Information

R1 and R2 are used to set the forward bias current $\left(I_{F}\right)$ of the TX or the RX series diode. The $I_{F}$ controls the Insertion Loss of the ANT to TX or ANT to RX path respectively.
For $\mathrm{R} 1=\mathrm{R} 2=69.8 \Omega$ the $\mathrm{I}_{\mathrm{F}}=0.1 \mathrm{~A}$
$\mathrm{R} 1=\mathrm{R} 2=2$ * $(\mathrm{VCC}-1.52 \mathrm{~V}) / \mathrm{I}_{\mathrm{F}}$.
R1 \& R2 must meet the following power requirement:
$\mathrm{P}_{\mathrm{R} 1 / 2}>\left(0.5^{*} I_{\mathrm{F}}\right)^{2}{ }^{*} \mathrm{R} 1$
R3 and R4 are used to set the forward bias current ( $\mathrm{I}_{\text {FShD }}$ ) in the RX shunt diode of the switch. The $\mathrm{I}_{\text {FShD }}$ controls the RX isolation.
For $\mathrm{R} 3=\mathrm{R} 4=3.6 \mathrm{k} \Omega$ the $\mathrm{I}_{\mathrm{FShD}}=0.01 \mathrm{~A}$
$\mathrm{R} 3=\mathrm{R} 4=2^{*}(18 \mathrm{~V}) / \mathrm{I}_{\mathrm{F}}$
These resistors must meet the following power requirement: $\mathrm{P}_{\mathrm{R} 3 / 4}>\left(0.5^{*} \mathrm{I}_{\mathrm{FShD}}\right)^{2 *} \mathrm{R} 3$

## Boost Biasing Information

D1 diode requirements: $\mathrm{VB}=40 \mathrm{~V}$, Forward Current $=200 \mathrm{~mA}$, Forward Surge Current $=750 \mathrm{~mA}$, reverse leakage current less than 400 uA at $125^{\circ} \mathrm{C}$

During boost period, VUREC (Pin 15) transient peak voltage and current can be as high as 24 V and 750 mA . Use recommend components from Parts List for proper current handling.

R7 and R8 are a resistive divider used to set the boost voltage. Use recommended components from Parts List for proper boost performance.

## Parts List ${ }^{8}$

| Component ID | Value | Package | Part Number | Manufacturer | Spec |
| :---: | :---: | :---: | :---: | :---: | :---: |
| MAMF-011180 | - | HQFN-20LD 5 mm | MAMF-011070 | MACOM | - |
| L1, L2 | 40 nH | $1 \times 0.5 \mathrm{~mm}$ | 0402CS-40NXJRW | Coilcraft | $620 \mathrm{~mA} / 125^{\circ} \mathrm{C}$ |
| L3, L5 | 10 nH | $1.6 \times 0.8 \mathrm{~mm}$ | LQW18AN10NG00D | Murata | $650 \mathrm{~mA} / 10 \mathrm{nH}$ |
| L4 | $10 \mu \mathrm{H}$ | $2.5 \times 2 \mathrm{~mm}$ | IFSC1008ABER100M01 | Vishay | $750 \mathrm{~mA} / 0.41 \Omega$ |
| C1 | Cu Shim | 0505 | - | - | - |
| C2 | 20 pF | 0505 | 800A200JTN250XT | ATC | $250 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C3, C7, C16 | 1 nF | 0603 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C4 | $1 \mu \mathrm{~F}$ | 0805 | CL21B105KBFNNNG | Samsung Electro-Mechanics | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C5 | 5.6 pF | 0603 | 600S5R6AT250XT | ATC | $250 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C6 | 100 pF | 0603 | - | - | $250 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C9, C13 | $2.2 \mu \mathrm{~F}$ | 1210 | - | - | $35 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C10 | 470 pF | 0402 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C11 | 100 nF | 0805 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C12 | 10 nF | 0805 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C14, C24 | $10 \mu \mathrm{~F}$ | 0603 | - | - | $10 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C15 | 10 pF | 0402 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C17 | 10 pF | 0505 | 800A100JT250X | ATC | $250 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| C18 | 0.3 pF | 0603 | 600S0R3AT250XT | ATC | $250 \mathrm{~V} / \pm 0.05 \mathrm{pF} / 125^{\circ} \mathrm{C}$ |
| C21, C22, C23 | 10 nF | 0603 | - | - | $50 \mathrm{~V} / 125^{\circ} \mathrm{C}$ |
| R1, R2 | $69.8 \Omega$ | 1206 | - | - | $0.25 \mathrm{~W} / 0.1 \% / 155^{\circ} \mathrm{C}$ |
| R3, R4 | $3.6 \mathrm{~K} \Omega$ | 0603 | - | - | $0.2 \mathrm{~W} / 0.1 \% / 155^{\circ} \mathrm{C}$ |
| R6, R18 | $0 \Omega$ | 0402 | - | - | $125^{\circ} \mathrm{C}$ |
| R7 | $1.6 \mathrm{M} \Omega$ | 0402 | - | - | $0.063 \mathrm{~W} / 1 \% / 155^{\circ} \mathrm{C}$ |
| R8 | $115 \mathrm{~K} \Omega$ | 0402 | - | - | $0.063 W / 1 \% / 155^{\circ} \mathrm{C}$ |
| R9 | $100 \Omega$ | 0402 | - | - | $125^{\circ} \mathrm{C}$ |
| D1 | - | SOT23-3 | CMPSH-3CE TR | Central Semiconductor | $750 \mathrm{~mA} / 40 \mathrm{~V} / 155^{\circ} \mathrm{C}$ |
| ANT, RX, TX | RF CONN | SMA | 142-0761-821 | Cinch Connectivity Solutions | - |
| DC CONN | DC CONN | 10PIN | - | - | 10 pin header |

8. MACOM datasheet performance was captured using components from manufacturers shown. These parts are critical to meet specified performance. All other parts must meet ratings specified but do not have specific manufacturer recommendations.

## Typical Performance Curves - Probed on the Sample Board (no PCB Bias Components)

 $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$

ANT Return Loss in TX ON state


TX Return Loss in TX ON state


## ANT to RX Insertion Loss



ANT Return Loss in RX ON state


RX Return Loss in RX ON state


Typical Performance Curves - Probed on the Sample Board (no PCB Bias Components) $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$

## ANT to RX Isolation



## ANT to TX Isolation



## Typical Performance Curves on the Sample Board optimized for 1-4.2 GHz performance VCC $=5 \mathrm{~V}, \mathrm{P}_{\text {IN }}=-5 \mathrm{dBm}$

## ANT to TX Insertion Loss (PCB loss de-embedded) ${ }^{9}$



ANT Return Loss in TX ON state


TX Return Loss in TX ON state


ANT to RX Insertion (PCB loss de-embedded) ${ }^{12}$


ANT Return Loss in RX ON state


RX Return Loss in RX ON state

9. For Insertion Loss plots, RF trace and connector losses are de-embedded .

## Typical Performance Curves on the Sample Board optimized for 1-4.2 GHz performance. $\mathrm{VCC}=5 \mathrm{~V}, \mathrm{P}_{\mathrm{IN}}=-5 \mathrm{dBm}$

## ANT to RX Isolation ${ }^{10}$



ANT to TX Isolation

10. ANT to RX isolation has strong dependence on board layout.

## Lead-Free 5 mm 20-Lead HQFN ${ }^{\dagger}$


${ }^{\dagger}$ Reference Application Note M538 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is NiPdAuAg

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[^0]:    1. Reference Application Note M513 for reel size information.
[^1]:    * Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

